Transient Voltage Suppression Diodes: TP5.0SMDJ Series

SMD Type 5000 W



Features

- 1. For surface mounted applications
- 2. RoHS compliant and halogen-free
- 3. Reliable low cost construction utilizing molded plastic technique
- 4. Glass passivated chip junction
- 5. Both bi-directional and uni-directional devices are available
- 6. Fast response time
- 7. Low leakage
- 8. Excellent clamping capability
- 5000W peak pulse power capability with a 10/1000 µs waveform, repetitive rate (duty cycle): 0.01%
- 10. High reliability application and automotive grade AEC Q101 qualified



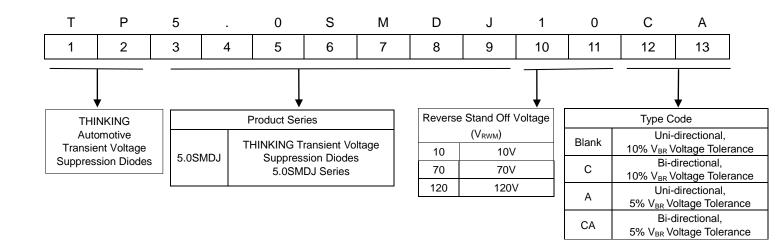
Recommended Applications

- 1. Telecommunication
- 2. Computer
- 3. Industrial device
- 4. Consumer electronic device
- 5. Automotive

Mechanical Data

- 1. Case: DO-214AB (SMC), molded plastic meets UL flammability rating 94V-0
- 2. Terminal: Matte Tin-plated leads, solderable per MIL-STD-750, Method 2026
- 3. Polarity: The band denotes cathode (Note: no polarity indicator for bi-directional devices)

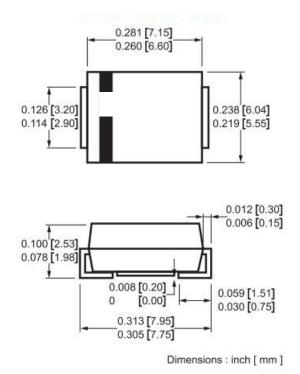
Part Number Code





Structures and Dimensions

SMC/DO214AB



■ Maximum Rating (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power dissipation at T_A=25 ${}^\circ\!\mathrm{C}$ by 10/1000µs waveform (Note1)	P _{PPM}	5000	W
Peak pulse current of 10/1000us waveform (Note1)	I _{PPM}	See Table	А
Peak forward surge current, 8.3ms single half sine wave on rated load (Note 2)	I _{FSM}	300	А
Power dissipation on infinite heatsink at TL=75 $^\circ\!\mathrm{C}$	PD	6.5	W
Operating junction and storage temperature range	T_J,T_STG	-55~+150	°C

Note: 1. Please refer to Fig. 5 for non-repetitive current pulse, and Fig. 1 for derated above T_A = 25 $^\circ\!{\rm C}$

2. 8.3ms single half sine-wave, or square wave that has a maximum of 4 pulses per minute.



Electrical Characteristics (T_A=25°C unless otherwise noted)

Part No. (Uni)	Part No. (Bi)	Reverse Stand off Voltage	Brea Vol	kage tage @ IT	Test Current	Maximum Clamping Voltage VC @ Ipp	Maximum Peak Pulse Current	Maximum Reverse Leakage IR @VRWM		king ode
		VRWM(V)	Min(V)	Max(V)	IT(mA)	VC(V)	lpp(A)	IR(μA)	UNI	BI
TP5.0SMDJ10A	TP5.0SMDJ10CA	10	11.1	12.3	1	17	294.12	5	5SAE	5DAE
TP5.0SMDJ11A	TP5.0SMDJ11CA	11	12.2	13.5	1	18.2	275.00	2	5SAF	5DAF
TP5.0SMDJ12A	TP5.0SMDJ12CA	12	13.3	14.7	1	19.9	252.00	2	5SAG	5DAG
TP5.0SMDJ13A	TP5.0SMDJ13CA	13	14.4	15.9	1	21.5	233.00	2	5SAK	5DAK
TP5.0SMDJ14A	TP5.0SMDJ14CA	14	15.6	17.2	1	23.2	216.00	2	5SAM	5DAM
TP5.0SMDJ15A	TP5.0SMDJ15CA	15	16.7	18.5	1	24.4	205.00	2	5SAP	5DAP
TP5.0SMDJ16A	TP5.0SMDJ16CA	16	17.8	19.7	1	26	193.00	2	5SAR	5DAR
TP5.0SMDJ17A	TP5.0SMDJ17CA	17	18.9	20.9	1	27.6	181.00	2	5SAT	5DAT
TP5.0SMDJ18A	TP5.0SMDJ18CA	18	20	22.1	1	29.2	172.00	2	5SAV	5DAV
TP5.0SMDJ19A	TP5.0SMDJ19CA	19	21.1	23.3	1	30.8	162.40	2	5SAX	5DAX
TP5.0SMDJ20A	TP5.0SMDJ20CA	20	22.2	24.5	1	32.4	155.00	2	5SAZ	5DAZ
TP5.0SMDJ22A	TP5.0SMDJ22CA	22	24.4	26.9	1	35.5	141.00	2	5SBE	5DBE
TP5.0SMDJ24A	TP5.0SMDJ24CA	24	26.7	29.5	1	38.9	129.00	2	5SBF	5DBF
TP5.0SMDJ26A	TP5.0SMDJ26CA	26	28.9	31.9	1	42.1	119.00	2	5SBG	5DBG
TP5.0SMDJ28A	TP5.0SMDJ28CA	28	31.1	34.4	1	45.4	110.00	2	5SBK	5DBK
TP5.0SMDJ30A	TP5.0SMDJ30CA	30	33.3	36.8	1	48.4	103.00	2	5SBM	5DBM
TP5.0SMDJ33A	TP5.0SMDJ33CA	33	36.7	40.6	1	53.3	93.90	2	5SBP	5DBP
TP5.0SMDJ36A	TP5.0SMDJ36CA	36	40	44.2	1	58.1	86.10	2	5SBR	5DBR
TP5.0SMDJ40A	TP5.0SMDJ40CA	40	44.4	49.1	1	64.5	77.60	2	5SBT	5DBT
TP5.0SMDJ43A	TP5.0SMDJ43CA	43	47.8	52.8	1	69.4	72.10	2	5SBV	5DBV
TP5.0SMDJ45A	TP5.0SMDJ45CA	45	50	55.3	1	72.7	68.80	2	5SBX	5DBX
TP5.0SMDJ48A	TP5.0SMDJ48CA	48	53.3	58.9	1	77.4	64.70	2	5SBZ	5DBZ
TP5.0SMDJ51A	TP5.0SMDJ51CA	51	56.7	62.7	1	82.4	60.70	2	5SCE	5DCE
TP5.0SMDJ54A	TP5.0SMDJ54CA	54	60	66.3	1	87.1	57.50	2	5SCF	5DCF
TP5.0SMDJ58A	TP5.0SMDJ58CA	58	64.4	71.2	1	93.6	53.50	2	5SCG	5DCG

Note:

1. Add suffix "C" or "CA" after part number to specify Bi-directional devices.

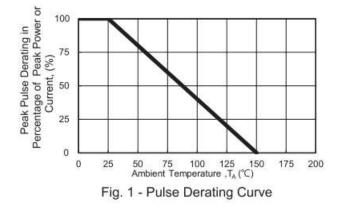
2. For bidirectional type having V_{RWM} of 10 volts and under, the I_R limit is doubled.

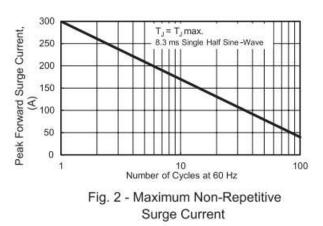
Transient Voltage Suppression Diodes: TP5.0SMDJ Series



SMD Type 5000 W

■ Rate and Characteristic Curve (T_A=25°C unless otherwise noted)





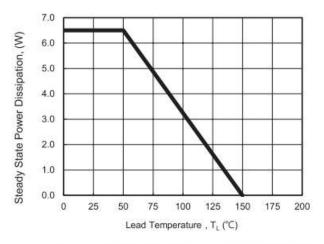
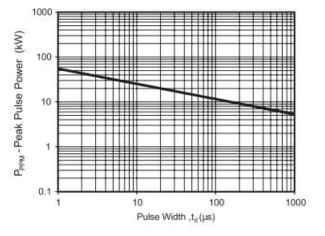


Fig. 3 - Steady State Power Derating Curve





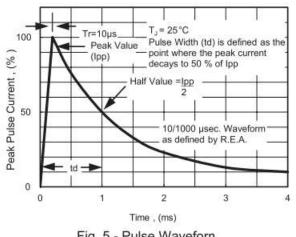


Fig. 5 - Pulse Waveforn

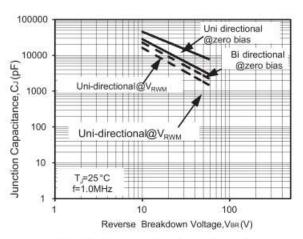
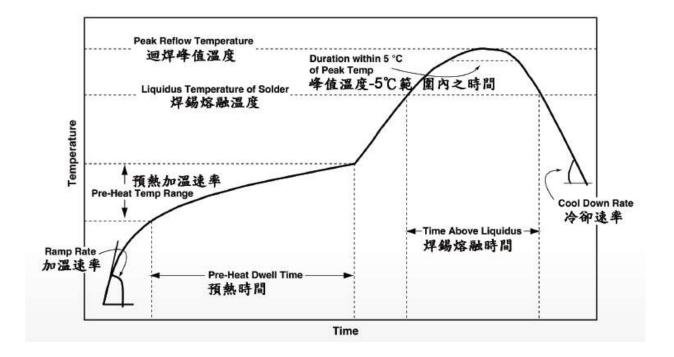


Fig. 6 - Typical Junction Capacitance



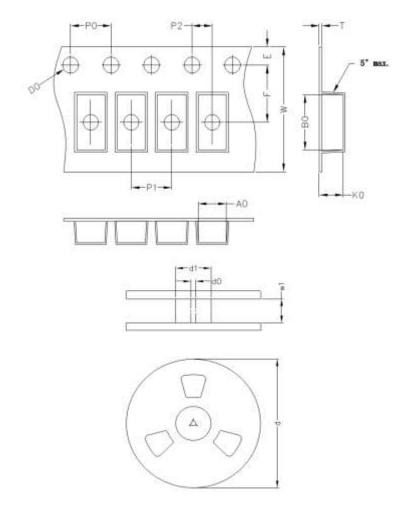
IR-reflow soldering profile



LEAD(Pb)-FREE SOLDER(SnAgCu) REFLOW PROFILE ATTRIBUTES				
PROFILE ATTRIBUTE	PROFILE ATTRIBUTE			
Peak Reflow Temperature	250(+10/-5) °C			
Time within 5 $^\circ\!\!\mathbb{C}$ of Peak Temperature	30s max			
Liquidus Temperatura of Solder	217 ℃			
Cool Down Rate	6 °C/s max			
Time above Liquidus	60s to 150s			
Pre-heat Temperature Range	150℃ to 200℃			
Pre-heat Dwell Time	60s to 120s			
Maximum Ramp Rate	3 °C/s max			



Packaging



ltem	Symbol	DO-214AB (SMC)		
item	Symbol	Unit: mm		
Carrier width	A0	6.05		
Carrier length	B0	8.31		
Carrier depth	K0	2.54		
Sprocket hole	D0	1.55		
Sprocket hole position	E	1.75		
Punch hole position	F	7.50		
Sprocket hole pitch	P0	4.00		
Carrier pitch	P1	8.00		
Embossment center	P2	2.00		
Tape thickness	Т	0.25		
Tape width	W	16.00		
Reel outside diameter	d (13")	330.00		
Reel inner diameter	d1	75		
Feed hole diameter	d0	13.50		
Reel inner width	w1	17.00		

Note:The tolerance of carrier tape and top cover is ±0.1mm, and the tolerance of reel is ±2mm

Quantity

Package	Reel Size	Reel	Inner Box	
Туре	inch	Kpcs	Kpcs	
DO-214AB	13	3	6	

Warehouse Storage Conditions of product

- Storage Condition:
- 1. Storage Temperature: $15 \sim 30^{\circ}$ C
- 2. Relative Humidity: \leq 75%RH
- 3. Keep away from corrosive atmosphere and sunlight.
- Period of Storage: 1 year.